

PE4150

UltraCMOS™ Low Frequency Passive Mixer with Integrated LO Amplifier

Features

- Ultra-high linearity Quad MOSFET array with integrated LO amplifier
- Ideal for mobile radio and Up/down conversion applications
- Low conversion loss
- High LO Isolation
- Packaged in small 4x4x0.85mm 20-lead QFN

Product Description

The PE4150 is an ultra-high linearity Quad MOSFET mixer with an integrated LO amplifier. The LO amplifier allows for LO drive levels of less than 0dBm to produce IIP3 values similar to a Quad MOSFET Array driven with a 15 dBm LO drive. The PE4150 operates with differential signals at the RF and IF ports and the integrated LO buffer amplifier drives the mixer core. It can be used as an upconverter or a downconverter.

The PE4150 is manufactured on Peregrine's UltraCMOS™ process, a patented variation of silicon-on-insulator (SOI) technology on a sapphire substrate, offering the performance of GaAs with the economy and integration of conventional CMOS.

Figure 1. Functional Diagram

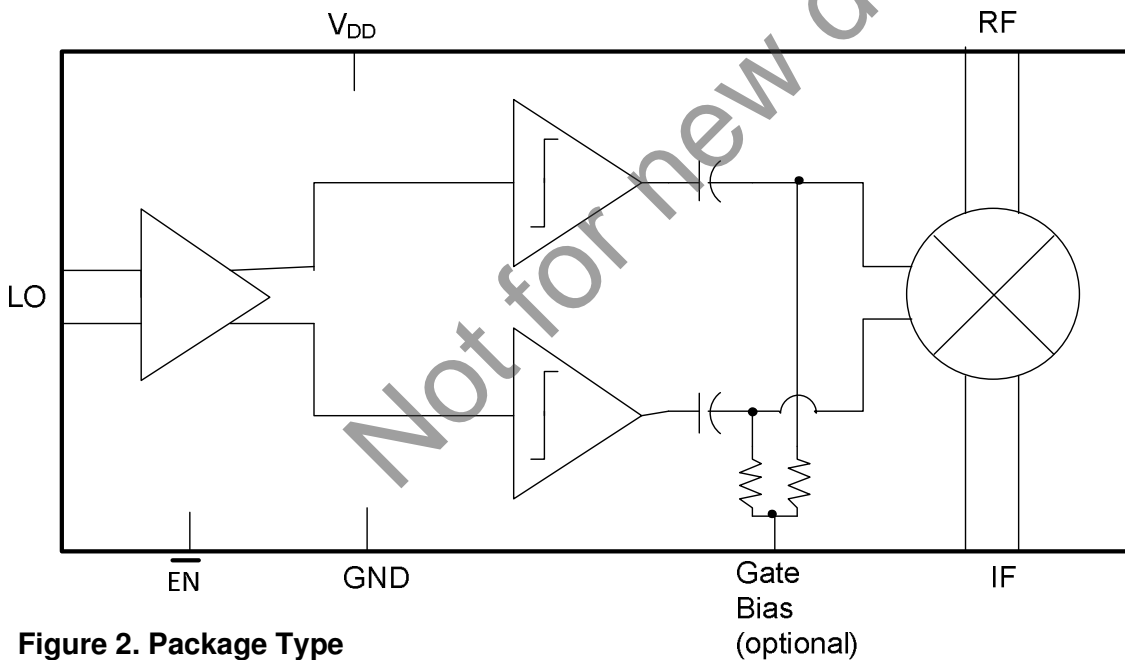


Figure 2. Package Type

4x4x.085 mm 20-Lead QFN

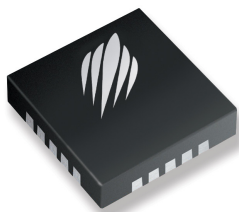


Table 1. AC and DC Electrical Specifications ($V_{DD} = 2.9$ to 3.1 V, Temperature = -40 to $+85$ °C unless specified otherwise)

Parameters	Min	Typ	Max	Units
Current Drain (a function of frequency)		8	12	mA
Off state leakage current			20	μ A
RF Input Frequency				
VHF Band	136		174	MHz
UHF1 Band	380		470	MHz
UHF2 Band	450		520	MHz
700 MHz	764		776	MHz
800 MHz	851		870	MHz
900 MHz	935		941	MHz
LO Frequency				
VHF Band	245.65		283.65	MHz
UHF1 Band	270.35		360.35	MHz
UHF2 Band	340.35		410.35	MHz
700 MHz	873.65		885.65	MHz
800 MHz	741.35		760.35	MHz
900 MHz	825.35		831.35	MHz
IF Output Frequency	44.85		109.65	MHz
LO Input Power	-10		-6	dBm
RF Input Power			2	dBm
Conversion Loss				
VHF, UHF1, UHF2		6.5	8	dB
700, 800, and 900 MHz		7.5	8.7	dB
3 rd Order Input Intercept (IIP3) ²	20	25		dBm
2 nd Order Input Intercept (IIP2)				
VHF, UHF1, UHF2	41	60		dBm
700, 800 and 900 MHz	35	50		dBm
RF to IF Isolation ¹				
VHF, UHF1, UHF2	35	50		dB
700, 800 and 900 MHz	25	45		dB
LO to IF Isolation	20	30		dB
LO to RF Isolation	25	30		dB

Notes: 1. The RF to IF Isolation is measured with an input frequency equal with IF.
2. IIP3 is measured with two tones at 0 dBm, 100kHz spacing

Figure 3. Pin Configuration (Top View)

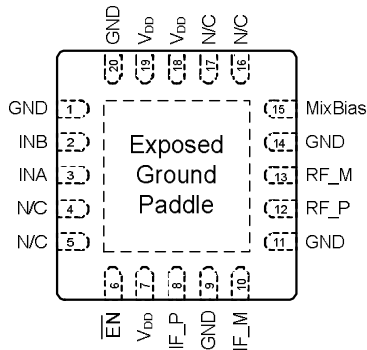


Table 2. Pin Descriptions

Pin #	Symbol	Description
1	GND	Ground
2	INB	Negative LO Input
3	INA	Positive LO Input
4	N/C	No Connect
5	N/C	No Connect
6	EN	Enable Pin (active low)
7	V _{DD}	V _{DD}
8	IF_P	Positive IF port
9	GND	Ground
10	IF_M	Negative IF port
11	GND	Ground
12	RF_P	Positive RF Input
13	RF_M	Negative LO Input
14	GND	Ground
15	MixBias	External Mixer Bias
16	N/C	No Connect
17	N/C	No Connect
18	V _{DD}	V _{DD}
19	V _{DD}	V _{DD}
20	GND	Ground
Pad	GND	Exposed Ground Paddle

The RF and IF pins are differential signals connected directly to the passive mixer. The LO input can be differential or single-ended.

Table 3. Operating Ranges

Symbol	Parameters/Conditions	Min	Typ	Max	Units
V _{DD}	V _{DD} Power Supply Voltage	2.9	3.0	3.1	V
T _{OP}	Operating temperature range	-40		85	°C

Moisture Sensitivity Level

The Moisture Sensitivity Level rating for the PE4150 in the 4x4x0.85 mm 20-lead QFN package is MSL3.

Table 4. Absolute Maximum Ratings

Symbol	Parameters/Conditions	Min	Max	Units
V _{DD}	Supply Voltage		4.0	V
V _{DS}	Maximum DC plus peak AC across drain-source		±3.3	V
I _{DS-DC}	Maximum DC current across drain-source		6	mA
I _{DS-AC}	Maximum AC current across drain-source		36	mA _{p-p}
T _{ST}	Storage temperature range	-65	150	°C
T _J	Operating Junction Temperature		125	°C
V _{ESD}	ESD Voltage (HBM, MIL_STD 883 Method 3015.7)		1000	V

Exceeding absolute maximum ratings may cause permanent damage. Operation should be restricted to the limits in the Operating Ranges table. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.

Electrostatic Discharge (ESD) Precautions

When handling this UltraCMOS™ device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the specified rating.

Latch-Up Avoidance

Unlike conventional CMOS devices, UltraCMOS™ devices are immune to latch-up.

Device Description

The PE4150 passive broadband Quad MOSFET array is designed for use in up-conversion and down-conversion applications for high performance systems such as mobile radios, cellular infrastructure equipment, and STB/CATV systems.

The PE4150 is an ideal mixer core for a wide range of mixer products, including module level solutions that incorporate baluns or other single-ended matching structures enabling three-port operation.

The performance level of this passive mixer is made possible by the very high linearity afforded by Peregrine's UltraCMOS™ process.

Evaluation Kit

The Mixer Evaluation Kit board was designed to ease customer evaluation of the PE4150 Quad MOSFET Mixer with integrated LO amplifier.

The RF and IF ports are connected through 50ohm transmission lines and 1:4 transmission line transformers to J5 and J7, respectively. The LO ports are connected through 50 Ω transmission lines to J4 and J6, respectively, and can support either a single-ended or differential signal drive. With a single-ended input, no termination is needed on the un-used port.

The board is constructed of a two metal layer FR4 with a total thickness of 0.062". The bottom layer provides ground for the RF transmission lines. The transmission lines were designed using a coplanar waveguide with ground plane model using a trace width of 0.037", trace gaps of 0.008", dielectric thickness of 0.059" and metal thickness of 0.0015".

J3 provides an optional external DC bias that can be applied to the LO input, if there is DC component to the applied RF input. To use this option, transformers T2 and T3 must be carefully chosen to allow the use of a non-zero common-mode level.

J9 can be used to enable or disable the part. The chip enable/EN is active low.

De-coupling capacitors are provided on the V_{DD} traces. These capacitors should be placed as close to the DV_{DD} pin as possible.

Figure 4. Evaluation Board Layout

Peregrine Specification 101-0201-00A

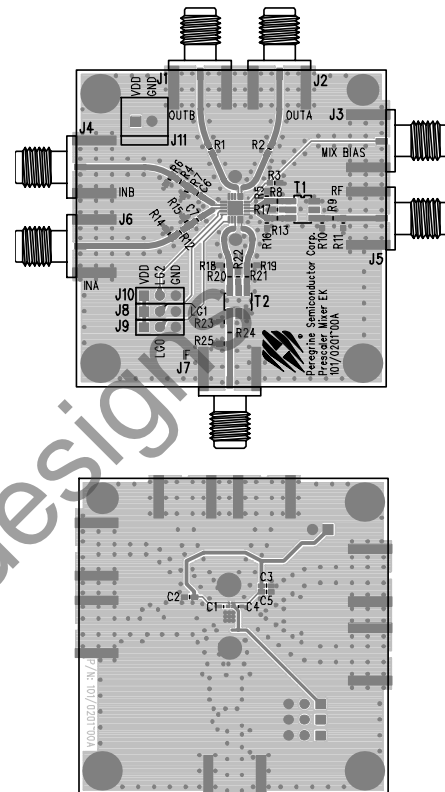
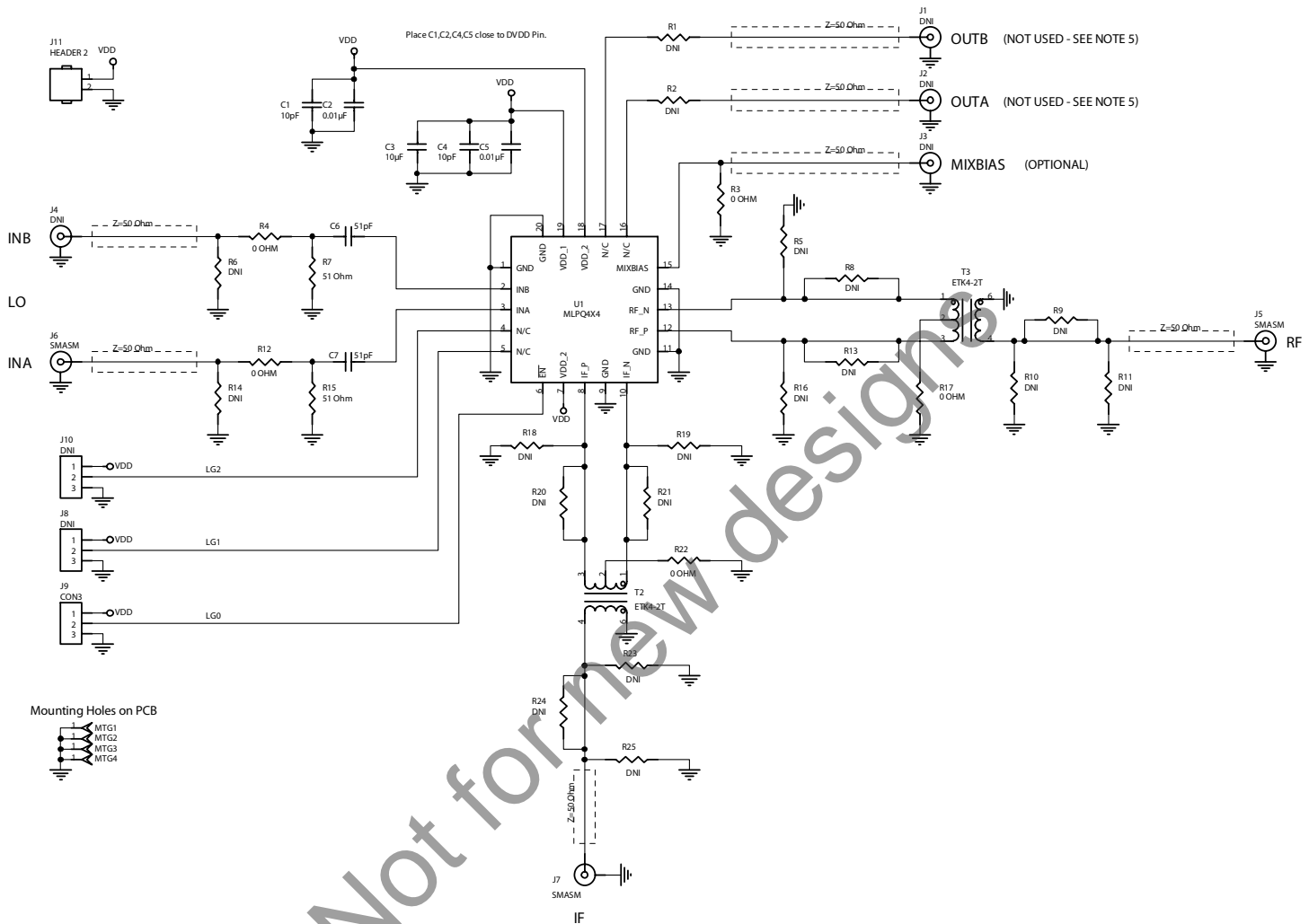


Figure 5. Evaluation Board Schematic
Peregrine Specification 102-0396



NOTES:

1. USE 101-0201-00A PCB.
2. CAUTION:
CONTAINS PARTS AND ASSEMBLIES SUSCEPTIBLE
TO DAMAGE BY ELECTROSTATIC DISCHARGE (ESD)
3. LO INPUT CAN BE DIFFERENTIAL OR SINGLE ENDED (INA/INB)
4. WITH SINGLE ENDED LO INPUT, NO TERMINATION IS NEEDED ON UNUSED PORT.
5. PINS 16 AND 17 ARE INTERNALLY DISCONNECTED.

Typical Performance Plots

Figure 6. Conversion Loss vs Temperature
($V_{DD} = 3V$; LO Pwr = -10 dBm)

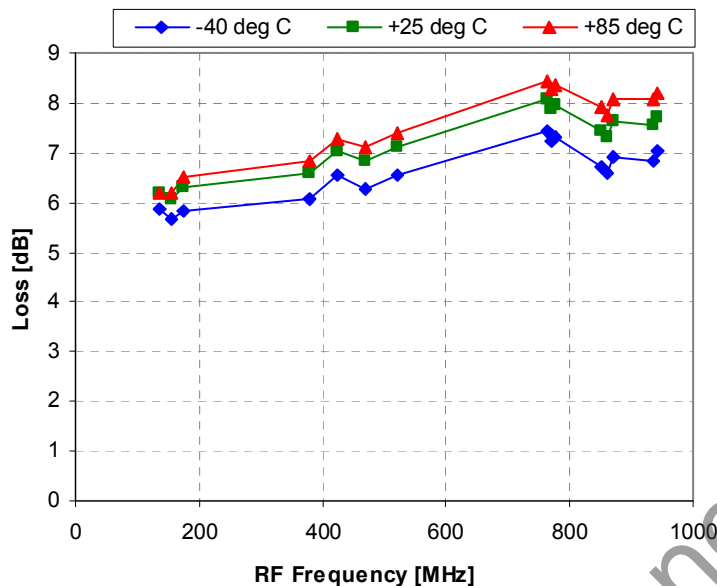


Figure 7. Conversion Loss vs LO Power & V_{DD}
(Temp = 25°C)

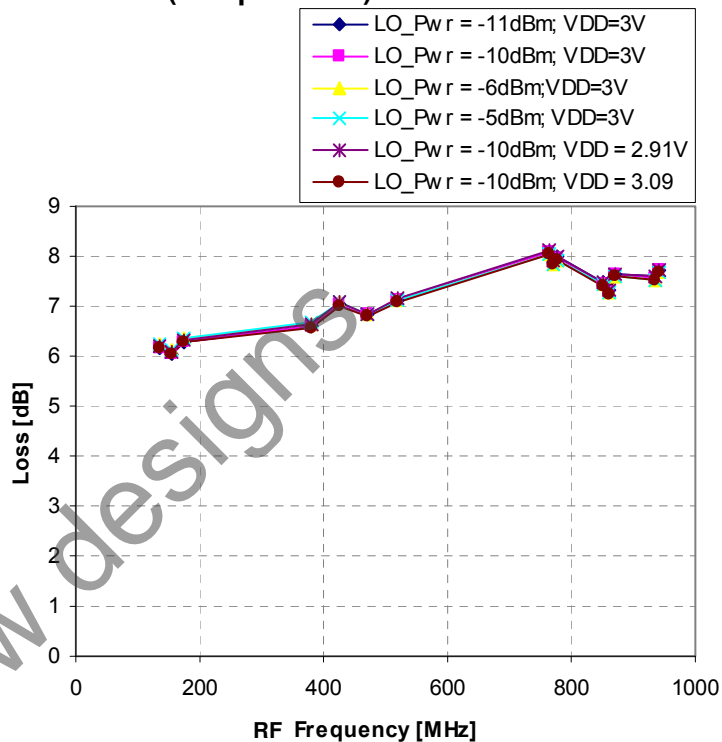


Figure 8. Linearity vs Temperature
($V_{DD} = 3V$; LO Pwr = -10 dBm)

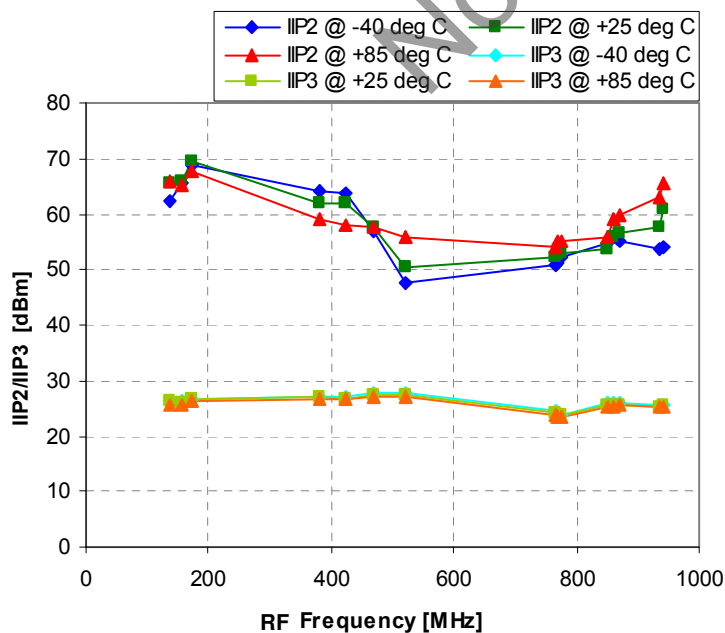
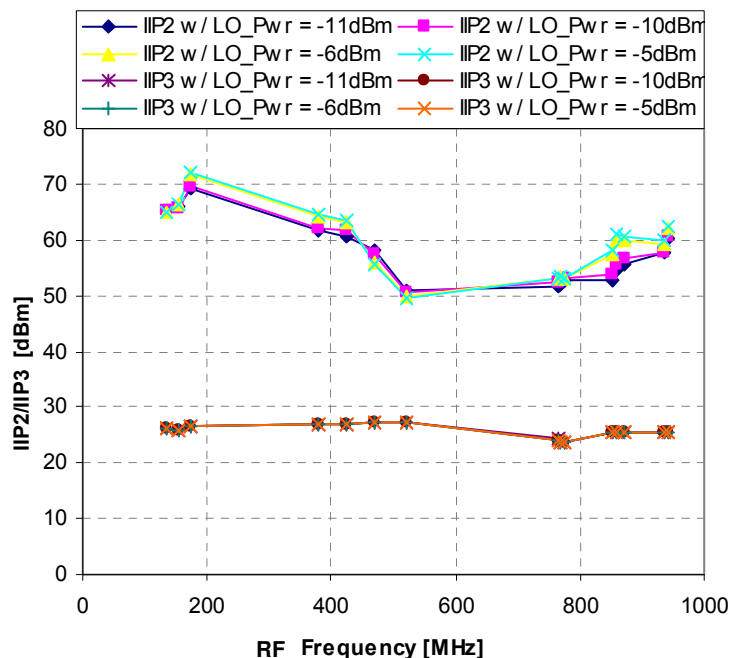


Figure 9. Linearity vs LO Power
($V_{DD} = 3V$; Temp = +25°C)



Typical Performance Plots

Figure 10. Linearity vs V_{DD}

(Temp = +25°C; LO Pwr = -10 dBm)

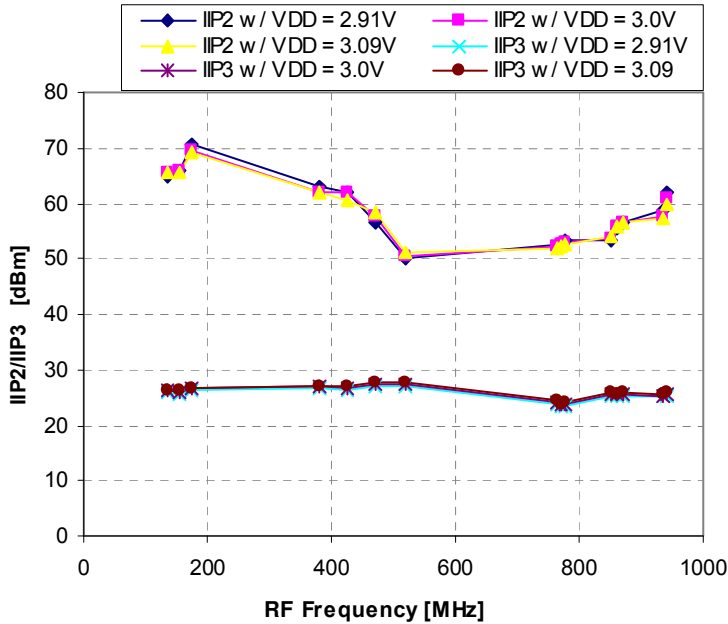


Figure 11. Isolation vs Temperature

(V_{DD} = 3V; LO Pwr = -10 dBm)

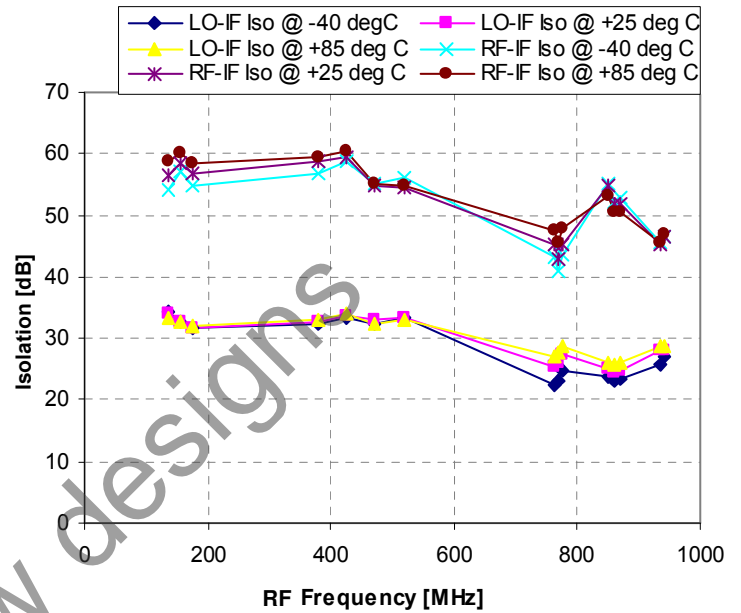


Figure 12. Isolation vs LO Power

(V_{DD} = 3V; Temp = +25°C)

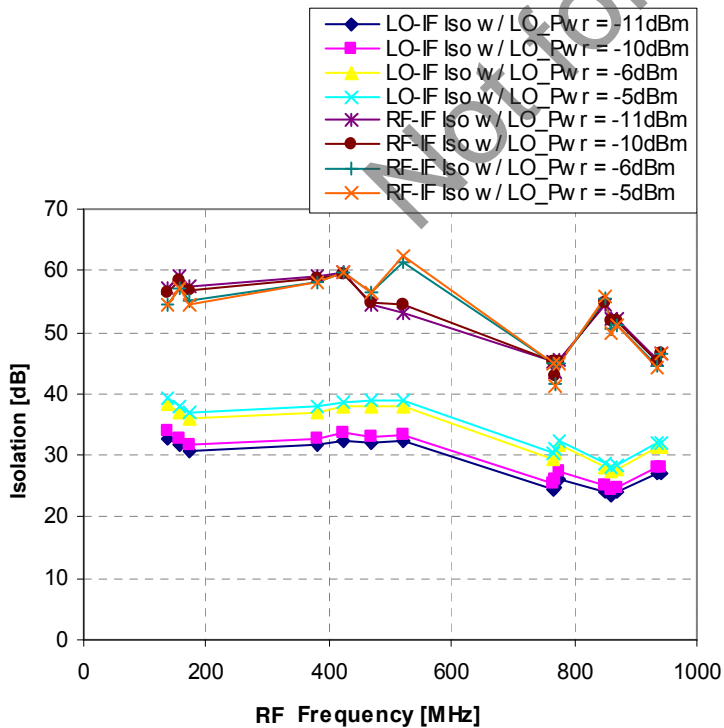


Figure 13. Isolation vs V_{DD}

(Temp = +25 deg C; LO Pwr = -10 dBm)

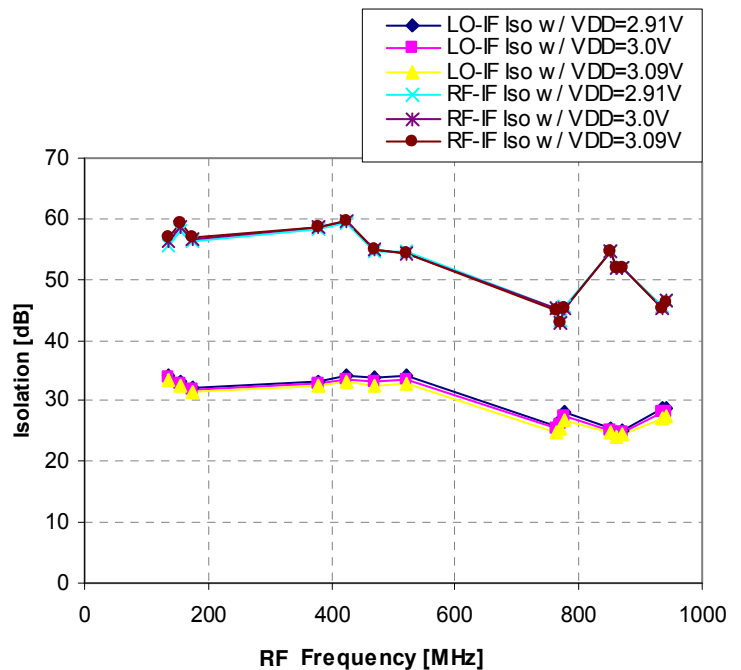
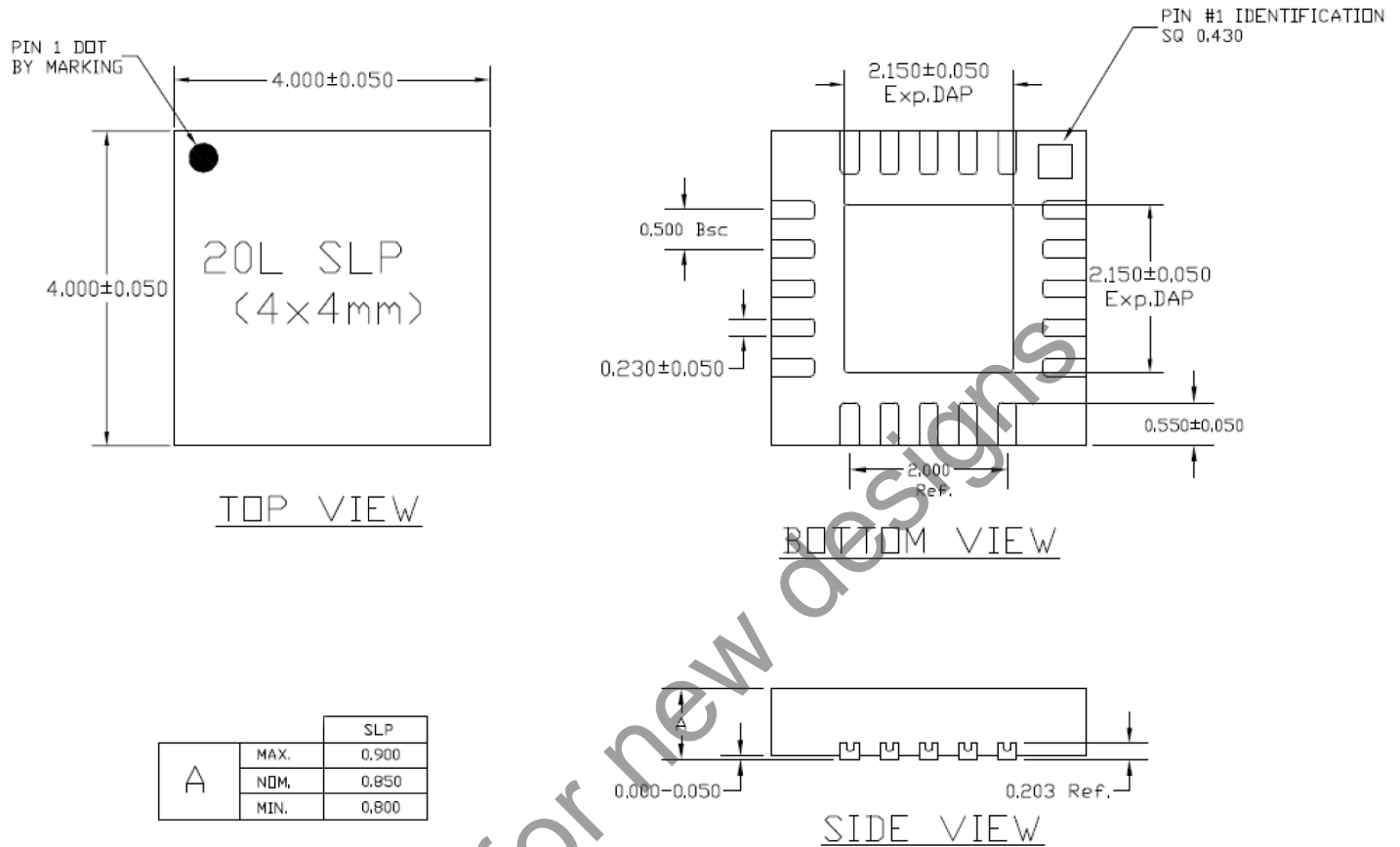


Figure 14. Package Drawing
4x4x0.85 mm 20-lead QFN



Sales Offices

The Americas

Peregrine Semiconductor Corporation

9380 Carroll Park Drive
San Diego, CA 92121
Tel: 858-731-9400
Fax: 858-731-9499

Europe

Peregrine Semiconductor Europe

Bâtiment Maine
13-15 rue des Quatre Vents
F-92380 Garches, France
Tel: +33-1-4741-9173
Fax : +33-1-4741-9173

High-Reliability and Defense Products

Americas

San Diego, CA, USA
Phone: 858-731-9475
Fax: 848-731-9499

Europe/Asia-Pacific

Parc Cezanne 1
380 Avenue Archimède
Parc de la Duranne
13857 Aix-En-Provence Cedex 3
France
Tel: +33(0)-4-4239-3361
Fax: +33(0)-4-4269-7227

Peregrine Semiconductor, Asia Pacific (APAC)

Shanghai, 200040, P.R. China
Tel: +86-21-5836-8276
Fax: +86-21-5836-7652

Peregrine Semiconductor, Korea

#B-2607, Kolon Tripolis, 210
Geumgok-dong, Bundang-gu, Seongnam-si
Gyeonggi-do, 463-943 South Korea
Tel: +82-31-728-3939
Fax: +82-31-728-3940

Peregrine Semiconductor K.K., Japan

601 Yaesu Kyodo Building
2-5-9 Yaesu, Chuo-ku
Tokyo 104-0028 Japan
Tel: +81-3-3527-9841
Fax: +81-3-3527-9848

For a list of representatives in your area, please refer to our
Web site at: www.psemi.com

Data Sheet Identification

Advance Information

The product is in a formative or design stage. The data sheet contains design target specifications for product development. Specifications and features may change in any manner without notice.

Preliminary Specification

The data sheet contains preliminary data. Additional data may be added at a later date. Peregrine reserves the right to change specifications at any time without notice in order to supply the best possible product.

Product Specification

The data sheet contains final data. In the event Peregrine decides to change the specifications, Peregrine will notify customers of the intended changes by issuing a CNF (Customer Notification Form).

The information in this data sheet is believed to be reliable. However, Peregrine assumes no liability for the use of this information. Use shall be entirely at the user's own risk.

No patent rights or licenses to any circuits described in this data sheet are implied or granted to any third party.

Peregrine's products are not designed or intended for use in devices or systems intended for surgical implant, or in other applications intended to support or sustain life, or in any application in which the failure of the Peregrine product could create a situation in which personal injury or death might occur. Peregrine assumes no liability for damages, including consequential or incidental damages, arising out of the use of its products in such applications.

The Peregrine name, logo, and UTSi are registered trademarks and UltraCMOS, HaRP, MultiSwitch and DuNE are trademarks of Peregrine Semiconductor Corp.